

2SC1775, 2SC1775A

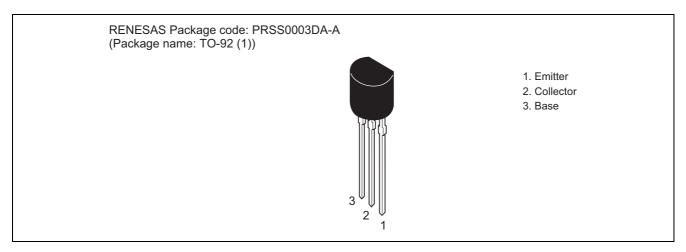
Silicon NPN Epitaxial

REJ03G0690-0200 (Previous ADE-208-1056) Rev.2.00 Aug.10.2005

Application

- Low frequency low noise amplifier
- Complementary pair with 2SA872/A

Outline



Absolute Maximum Ratings

 $(Ta = 25^{\circ}C)$

Item	Symbol	2SC1775	2SC1775A	Unit	
Collector to base voltage	V _{CBO}	90	120	V	
Collector to emitter voltage	V _{CEO}	90	120	V	
Emitter to base voltage	V _{EBO}	5	5	V	
Collector current	I _C	50	50	mA	
Collector power dissipation	Pc	300	300	mW	
Junction temperature	Tj	150	150	°C	
Storage temperature	Tstg	-55 to +150	-50 to +150	°C	

Electrical Characteristics

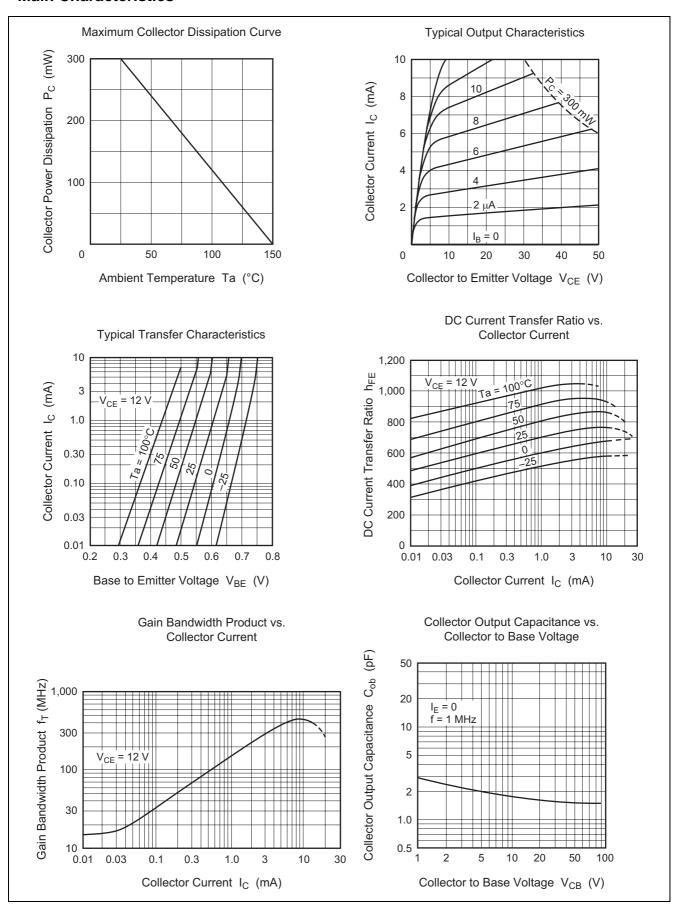
 $(Ta = 25^{\circ}C)$

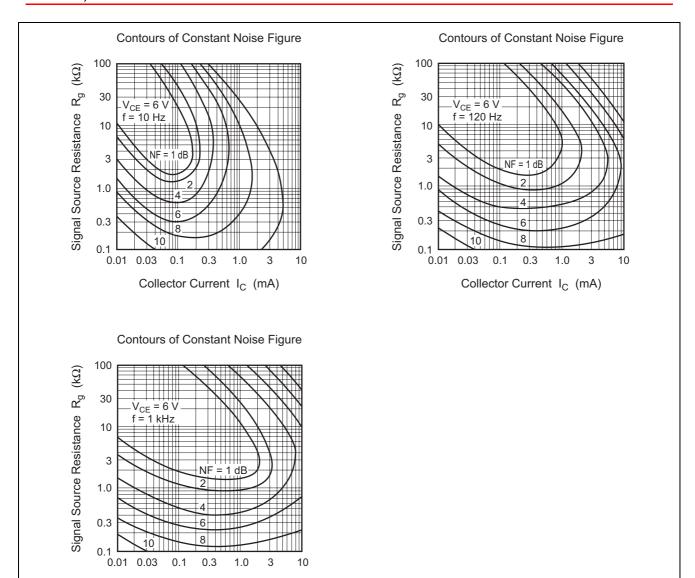
		:	2SC1775	5	2SC1775A				
Item	Symbol	Min	Тур	Max	Min	Тур	Max	Unit	Test conditions
Collector to emitter breakdown voltage	V _{(BR)CEO}	90	_	_	120	_	_	V	$I_C = 1 \text{ mA}, R_{BE} = \infty$
Collector cutoff current	I _{CBO}			0.5			_	μΑ	$V_{CB} = 75 \text{ V}, I_{E} = 0$
				_			0.5	μΑ	$V_{CB} = 100 \text{ V}, I_E = 0$
DC current transfer ratio	h _{FE1} *1	400		1200	400		1200		$V_{CE} = 12 \text{ V}, I_{C} = 2 \text{ mA}$
	h _{FE2}	160	-	_	160		_		$V_{CE} = 12 \text{ V},$ $I_{C} = 0.1 \text{ mA}$
Base to emitter voltage	V_{BE}	_	_	0.75	_	_	0.75	V	$V_{CE} = 12 \text{ V}, I_{C} = 2 \text{ mA}$
Collector to emitter saturation voltage	V _{CE(sat)}			0.5	-	-	0.5	٧	$I_C = 10 \text{ mA}, I_B = 1 \text{ mA}$
Gain bandwidth product	f⊤	_	200	_	_	200	_	MHz	$V_{CE} = 12 \text{ V}, I_{C} = 2 \text{ mA}$
Collector output capacitance	Cob	_	1.6	_	_	1.6	_	pF	$V_{CB} = 25 \text{ V}, I_E = 0,$ f = 1 MHz
Noise figure	NF	_	_	5.0	_	_	5.0	dB	$\begin{aligned} &V_{CE}=6~V,\\ &I_{C}=50~\mu\text{A},\\ &R_{g}=50~k\Omega \end{aligned} \qquad f=10~Hz$
		_	_	1.5	_	_	1.5	dB	f = 1 kHz

Note: 1. The 2SC1775/A is grouped by h_{FE1} as follows.

E	F		
400 to 800	600 to 1200		

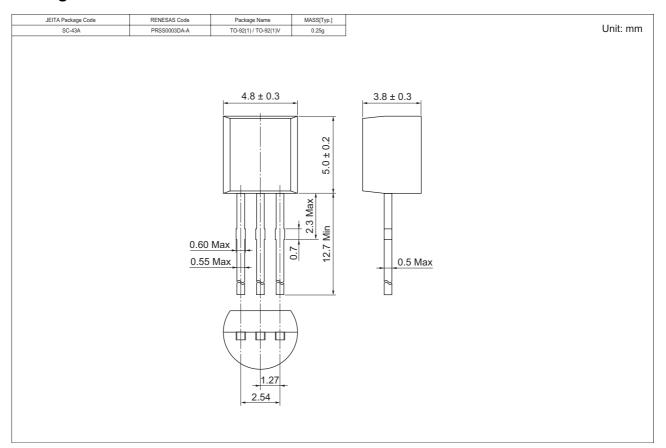
Main Characteristics





Collector Current I_C (mA)

Package Dimensions



Ordering Information

Part Name	Quantity	Shipping Container		
2SC1775AETZ	2500	Hold Box, Radial Taping		
2SC1775AFTZ				

Note: For some grades, production may be terminated. Please contact the Renesas sales office to check the state of production before ordering the product.

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